

**FR601
THRU
FR607**

Features

- Low Cost
- Low Leakage
- Low Forward Voltage Drop
- High Current Capability
- Fast Switching Speed For High Efficiency

**6 Amp Fast Recovery
Rectifier
50 to 1000 Volts**

Maximum Ratings

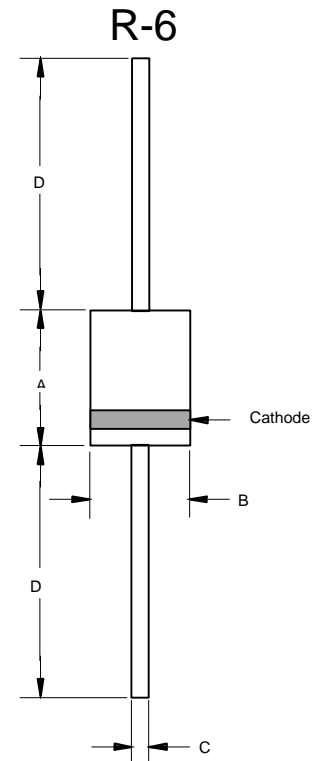
- Operating Temperature: -65°C to +150°C
- Storage Temperature: -65°C to +150°C

Microsemi Catalog Number	Device Marking	Maximum Recurrent Peak Reverse Voltage	Maximum RMS Voltage	Maximum DC Blocking Voltage
FR601	---	50V	35V	50V
FR602	---	100V	70V	100V
FR603	---	200V	40V	200V
FR604	---	400V	280V	400V
FR605	---	600V	420V	600V
FR606	---	800V	560V	800V
FR607	---	1000V	700V	1000V

Electrical Characteristics @ 25°C Unless Otherwise Specified

Average Forward Current	$I_{F(AV)}$	6 A	$T_A = 55^\circ\text{C}$
Peak Forward Surge Current	I_{FSM}	300A	8.3ms, half sine
Maximum Instantaneous Forward Voltage	V_F	1.3V	$I_{FM} = 6.0\text{A}; T_A = 25^\circ\text{C}$
Maximum DC Reverse Current At Rated DC Blocking Voltage	I_R	10 μA 150 μA	$T_A = 25^\circ\text{C}$ $T_A = 55^\circ\text{C}$
Maximum Reverse Recovery Time FR301-304 FR305 FR306-307	T_{rr}	150ns 250ns 500ns	$I_F=0.5\text{A}, I_R=1.0\text{A}, I_{rr}=0.25\text{A}$
Typical Junction Capacitance	C_J	150pF	Measured at 1.0MHz, $V_R=4.0\text{V}$

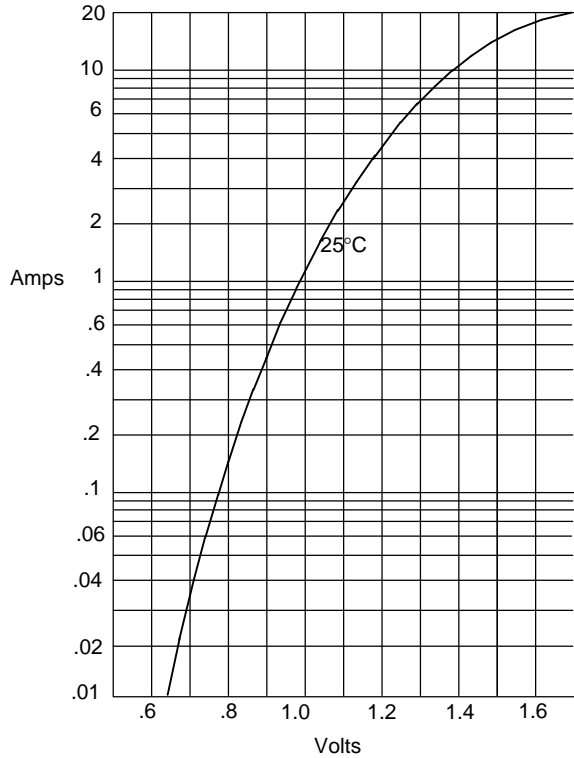
*Pulse Test: Pulse Width 300 μsec , Duty Cycle 1%



DIM	DIMENSIONS				NOTE
	INCHES		MM		
A	.340	.360	8.60	9.10	
B	.340	.360	8.60	9.10	
C	.048	.052	1.20	1.30	
D	1.000	---	25.40	---	

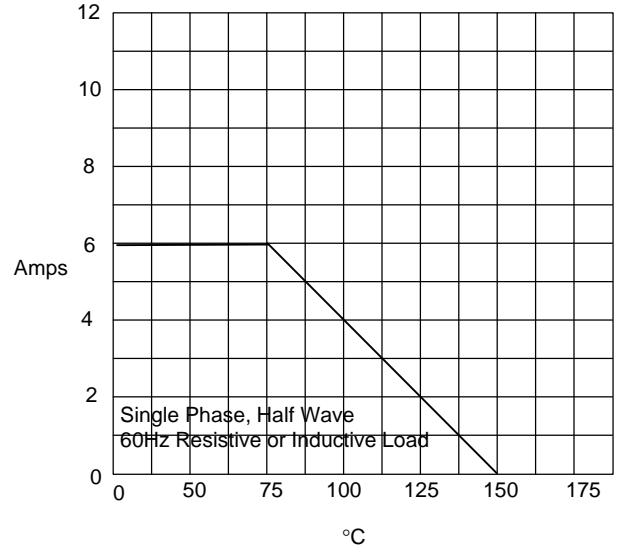
FR601 thru FR607

Figure 1
Typical Forward Characteristics



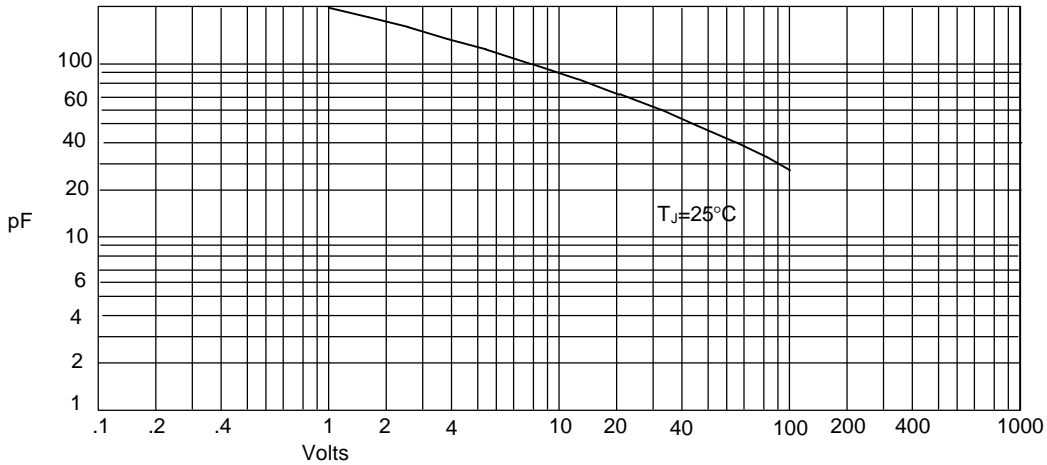
Instantaneous Forward Current - Amperes *versus*
Instantaneous Forward Voltage - Volts

Figure 2
Forward Derating Curve



Average Forward Rectified Current - Amperes *versus*
Ambient Temperature - °C

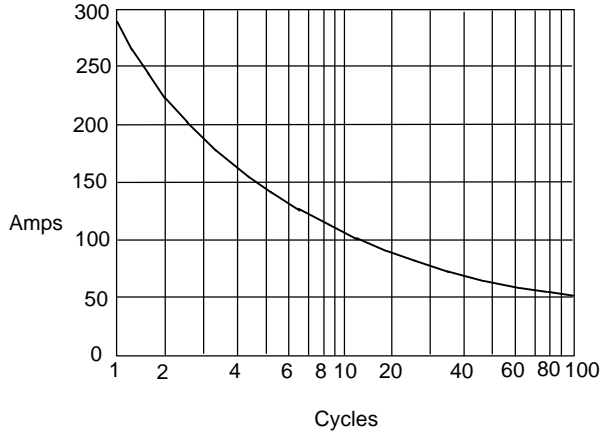
Figure 3
Junction Capacitance



Junction Capacitance - pF *versus*
Reverse Voltage - Volts

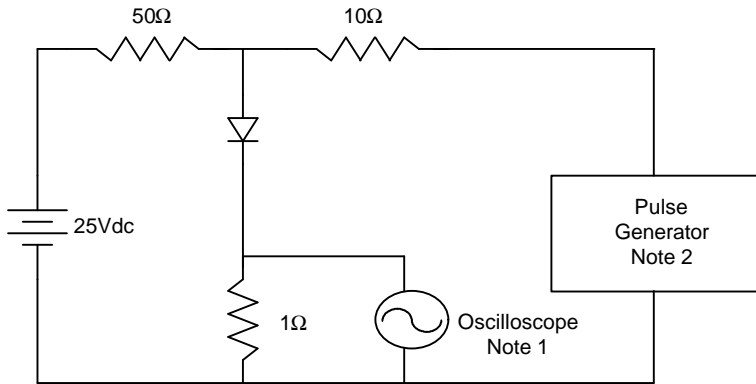
FR601 thru FR607

Figure 4
Peak Forward Surge Current



Peak Forward Surge Current - Amperes versus
Number Of Cycles At 60Hz - Cycles

Figure 5
Reverse Recovery Time Characteristic And Test Circuit Diagram



Notes:

1. Rise Time = 7ns max.
Input impedance = 1 megohm, 22pF
2. Rise Time = 10ns max.
Source impedance = 50 ohms
3. Resistors are non-inductive

